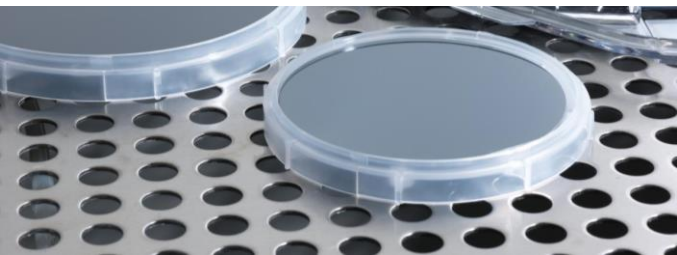




Summer school on wide-bandgap nitride devices

July 8-11 2019, Ghent, Belgium



From crystal growth

to final application



Co-organisers



InRel NPower

www.inrel-npower.eu

GaN GaNonCMOS

www.ganoncmos.eu

Agenda highlights

Keynote: Oliver Ambacher, University of Freiberg

Presentations from both industry and academia

EpiGaN, Fraunhofer IISB, ONSemiconductor, University of Padua, Robert Bosch, Siemens, PNO Innovation, AT&S, X-FAB and RECOM

Company visit to ONSemiconductor, Oudenaarde

Venue

The workshop takes place at

convention center *Het Pand*,

a former historical monastery in Ghent, Belgium

Registration

Participation is free of charge.

The total number of participants is limited.

Register on our website before June 23, 2019.

More information

www.inrel-npower.eu/SummerSchool2019



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